BTA208X-1000B

GENERAL DESCRIPTION

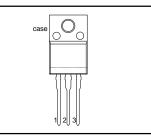
Passivated high voltage, high commutation triac in a full pack, plastic envelope. This triac is intended for use in motor control circuits where high blocking voltage, high static and dynamic dV/dt and high dl/dt can occur. This device will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	1000 8 65	V A A

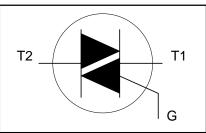
PINNING - SOT186A

PIN	DESCRIPTION			
1	main terminal 1			
2	main terminal 2			
3	gate			
case	isolated			



PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{drm}	Repetitive peak off-state voltages		-	1000	v
I _{T(RMS)}	RMS on-state current	full sine wave; T _{hs} ≤ 73 °C	-	8	A
I _{TSM}	Non-repetitive peak on-state current	full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$	-	65	Ą
l²t dI _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after triggering		-	71 21 100	A A²s A/µs
$\begin{array}{l} I_{GM} \\ V_{GM} \\ P_{GM} \\ P_{G(AV)} \end{array}$	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period	- - -	2 5 5 0.5	A V W W
T _{stg} T _j	Storage temperature Operating junction temperature	penou	-40 -	150 125	Ĵ Ĵ

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-	-	2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs} R _{th j-a}	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air	- -	- - 55	4.5 6.5 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current ¹	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01		T2	2+ G+	2	18	50	mA
		T2	2+ G- 🛛	2	21	50	mA
		T2	2- G-	2	34	50	mA
I_{L}	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
-			2+ G+	-	31	60	mA
		T2	2+ G- 🛛	-	34	90	mA
		T2	2- G-	-	30	60	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$		-	31	60	mA
ι _Η V _T	On-state voltage	$I_{T} = 10 \text{ A}$		-	1.3	1.65	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
0.		$V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{i} = 125 \text{ °C}$;	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{U} = V_{DRM(max)}; T_{j} = 125 \ ^{\circ}C$		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	1000	4000	-	V/µs
dl _{com} /dt	off-state voltage Critical rate of change of commutating current	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 ^{\circ}\text{C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ without snubber; gate open circuit	15	38	-	A/ms
t _{gt}		$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

¹ Device does not trigger in the T2-, G+ quadrant.

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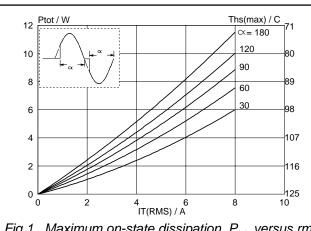
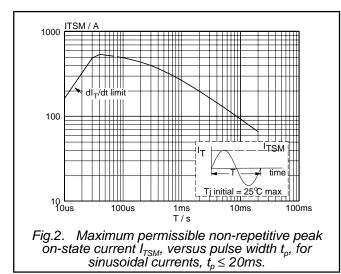
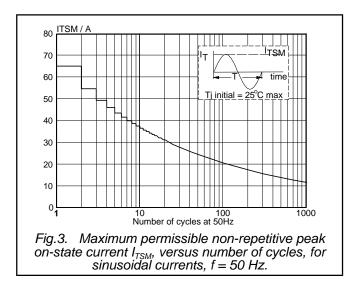
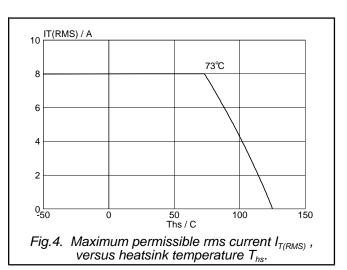


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.







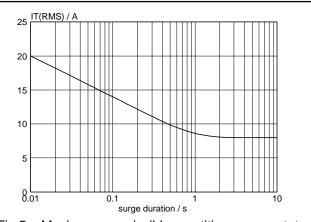
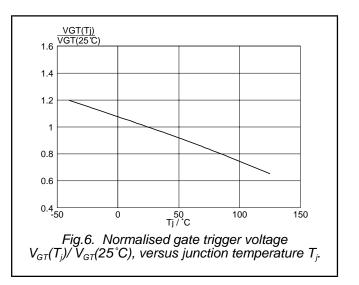
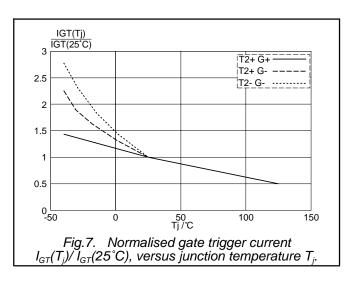
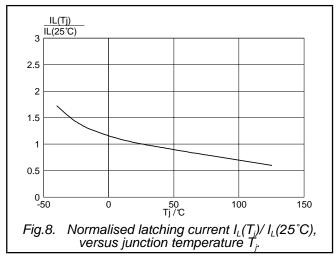


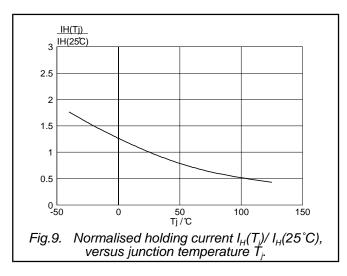
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 73$ °C.

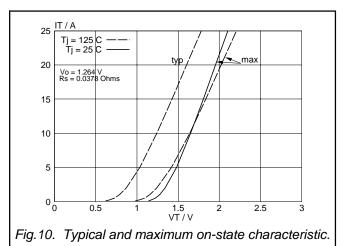


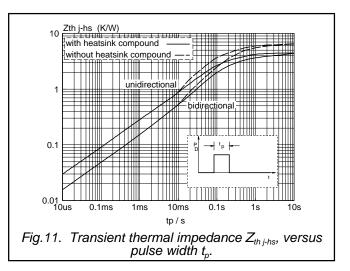
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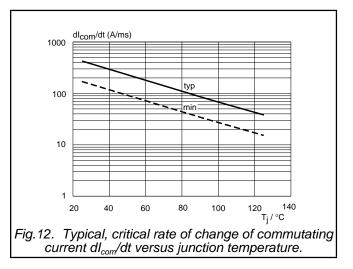








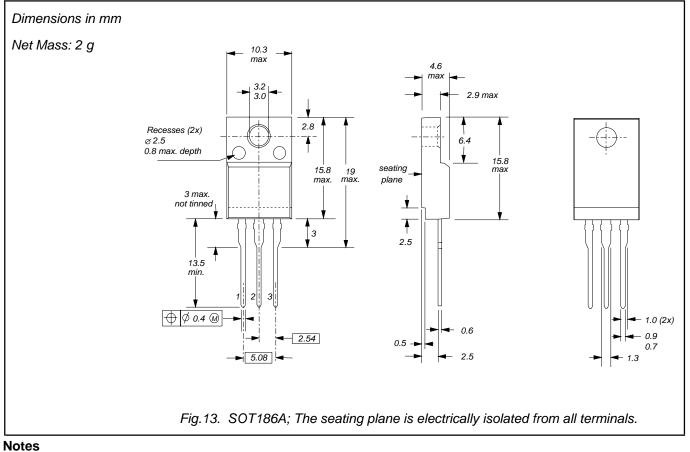




Product specification

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MECHANICAL DATA



Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

DATA SHEET STATUS						
PRODUCT STATUS ³	DEFINITIONS					
Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice					
Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product					
Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A					
	PRODUCT STATUS ³ Development Qualification					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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